NSN 5962-01-124-9550

Memory Microcircuit - Page 1 of 1



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Body Length:	
0.785 inches	
Body Width:	
0.302 inches	
Body Height:	
0.175 inches	
Maximum Power Diss	ipation Rating:
332.8 milliwatts	
Operating Tempuratu	re Range:
+0.0/+75.0 degrees cel	Isius
Storage Tempurature	Range:
-65.0/+150.0 degrees o	zelsius
Features Provided:	
Hermetically sealed an	d bipolar and programmable and w/enable
Inclosure Material:	
Ceramic	
Inclosure Configurati	on:
Dual-in-line	
Output Logic Form:	
Transistor-transistor log	gic
Input Circuit Pattern:	
6 input	
Terminal Surface Trea	atment:
Solder	
Voltage Rating And T	ype Per Characteristic:
7.0 volts power source	
Time Rating Per Chao	:teristic:
50.00 nanoseconds pr	ropagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Terminal Type And Q	uantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	